NSN 5962-01-063-5302



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-063-5302 **Body Length:** Between 0.755 inches and 0.790 inches **Body Width:** Between 0.265 inches and 0.300 inches **Body Height:** Between 0.155 inches and 0.175 inches **Maximum Power Dissipation Rating:** 307.2 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set type an/fps-115 **Features Provided:** Hermetically sealed and monolithic and positive outputs and bipolar **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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